

Specification SWT821-S

S	SC	CUSTOMER
Drawn	Approval	Approval



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SWT821-S

Description

This surface-mount LED comes in PLCC standard package dimension. It has a substrate made up of a molded plastic reflector sitting on top of a bent lead frame. The die is attached within the reflector cavity and the cavity is encapsulated by epoxy or silicone.

The package design coupled with careful selection of component materials allow these products to perform with high reliability in a larger temperature range - 40° to 100° . The high reliability feature is crucial to Automotive interior and Indoor ESS.



SWT821-S

Features

- White colored SMT package.
- Material : InGaN/SiC
- Encapsulating Resin : Silicon Resin
- High Reliability
- Suitable for all SMT assembly methods ; Suitable for all soldering methods
- RoHS Compliant

Applications

- Interior automotive
- Electronic Signs and Signals
- Office Automation, Electrical Appliances, Industrial Equipment

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2.	Absolute	maximum	ratings
	Absolute	maximam	ratings

Parameter	Symbol	Value	Unit
Power Dissipation	P _d	342	mW
Forward Current	I _F	90	mA
Peak Forward Current	I _{FM} *2	100	mA
Reverse Voltage (per die)	V _R	5	V
Operating Temperature	T _{opr}	-40 ~ +85	٥C
Storage Temperature	T _{stg}	-40 ~ +100	٥C

*1 Care is to be taken that power dissipation does not exceed the absolute maximum rating of the product. *2 *IFM* was measured at $T_W \leq 1$ msec of pulse width and D $\leq 1/10$ of duty ratio.

3. Electric characteristics

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Forward Voltage (per die)	V _F	<i>I_F</i> =60 mA	2.8	3.2	3.8	V
Reverse Current (per die)	I _R	$V_R = 5V$	-	-	10	μA
Luminance Intensity *1	I_V	<i>I_F</i> =60 mA	4000	5500	6500	mcd
Luminance Flux	Φ_V	<i>I_F</i> =60 mA	11	13.5	16	lm
Color Temperature	ССТ	<i>I_F</i> =60 mA	12000	-	4800	К
Viewing Angle *2	2 <i>θ</i> _{1/2}	<i>I_F</i> =60 mA	-	120	-	deg
Optical Efficiency	Ŋ _{op}	<i>I_F</i> =60 mA	-	70	-	lm/W
Thermal Resistance	Rth _{ja}	<i>I_F</i> =60 mA	-	65	-	K/W

*1. The luminous intensity IV was measured at the peak of the spatial pattern which may not be aligned with the mechanical axis of the LED package. Luminous Intensity Measurement allowance is $\pm 10\%$

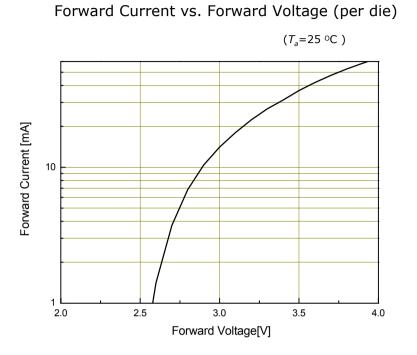
*2. 2θ ¹/₂ is the off-axis where the luminous intensity is 1/2 of the peak intensity.

*3. Rthja results from mounting on PCB FR4(pad size \geq 16mm2 per pad, thickness \Rightarrow 0.6mm)

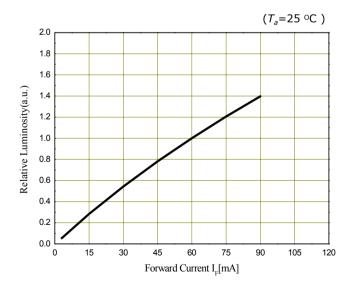


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4. Optical characteristics



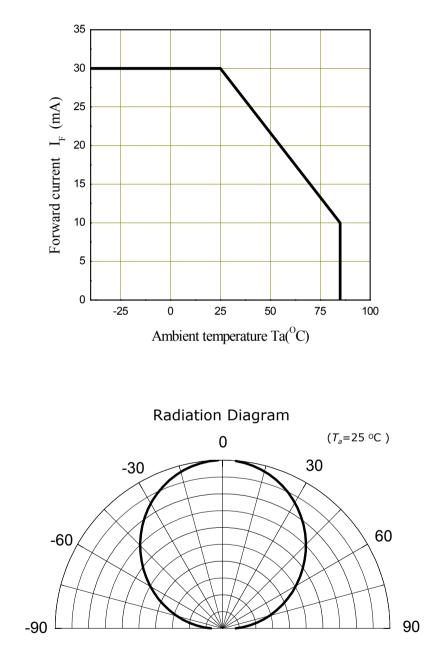
Relative Luminous Intensity vs Forward Current



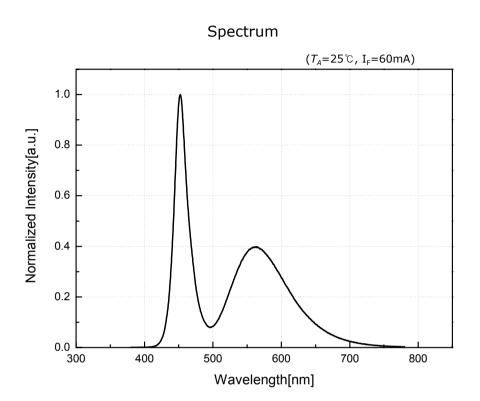


4. Optical characteristics

Ambient Temperature vs. Allowable Forward Current (per die)



4. Optical characteristics



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5. Rank of SWT821-S

§.Rank Name

X1	X2	Х3
VF	IV	CIE

§.Forward Voltage[V]

rank name	min	max	Unit
Z1	3.0	3.1	V
Z2	3.1	3.2	
Z3	3.2	3.3	
A1	3.3	3.4	
A2	3.4	3.5	

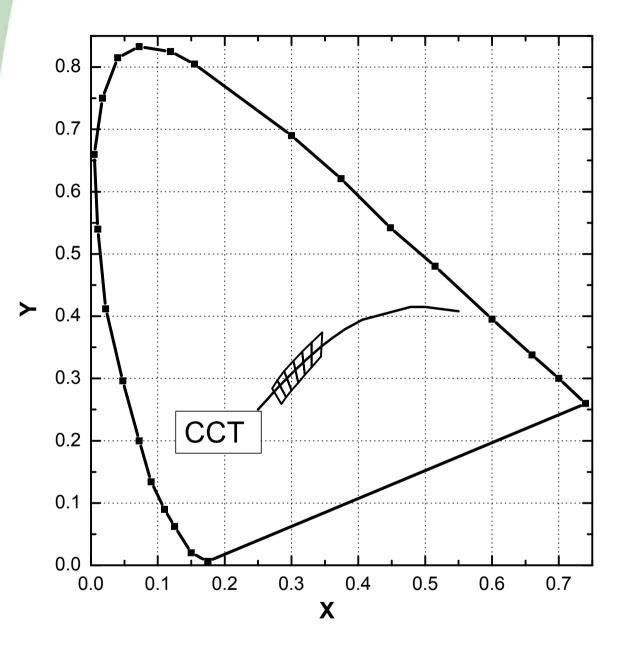
§.Luminous Intensity [IV]

rank name	min	max	Unit
М	4000	5000	mcd
N	5000	6500	

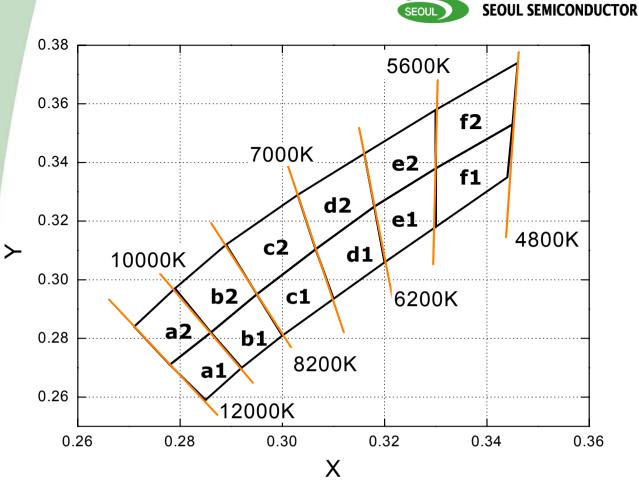
[Note] All measurements were made under the standardized environment of SSC.







Technical Data Sheet



COLOR RANK

<IF=60mA, Ta=25℃>

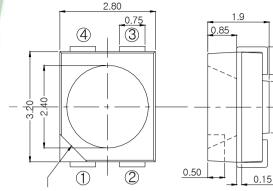
		- 2			11		
a1		a2		b1		b2	
X	Y	X	Y	X	Y	X	Y
0.285	0.259	0.278	0.271	0.292	0.27	0.286	0.282
0.292	0.27	0.286	0.282	0.3	0.281	0.295	0.295
0.286	0.282	0.279	0.297	0.295	0.295	0.289	0.312
0.278	0.271	0.271	0.284	0.286	0.282	0.279	0.297
c1		c2		d1		d2	
X	Y	X	Y	X	Y	X	Y
0.3	0.281	0.295	0.295	0.31	0.2935	0.3065	0.3104
0.31	0.2935	0.3065	0.3104	0.32	0.306	0.318	0.325
0.3065	0.3104	0.303	0.329	0.318	0.325	0.316	0.343
0.295	0.295	0.289	0.312	0.3065	0.3104	0.303	0.329
e1		e2	e2			f2	
X	Y	X	Y	X	Y	X	Y
0.32	0.306	0.318	0.325	0.33	0.318	0.33	0.338
0.33	0.318	0.33	0.338	0.344	0.335	0.345	0.353
0.33	0.338	0.33	0.358	0.345	0.353	0.346	0.374
0.318 ^{su}	remon 325 cert	aint o.Site Co	lor 6.343 ate	^{₅ :} ± 0⁰.3 3	0.338	0.33	0.358



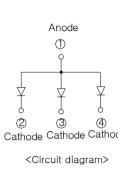
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Recommended Solder Pattern

7.outline dimension

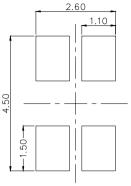


ATTENTION MARKING ON LED IS COMMON ANODE(+)



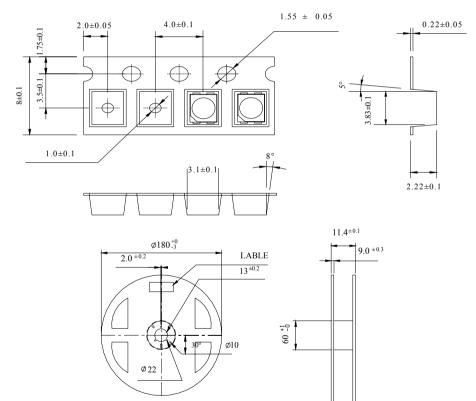
0.80

20



(Tolerance: ± 0.2 , Unit: mm)

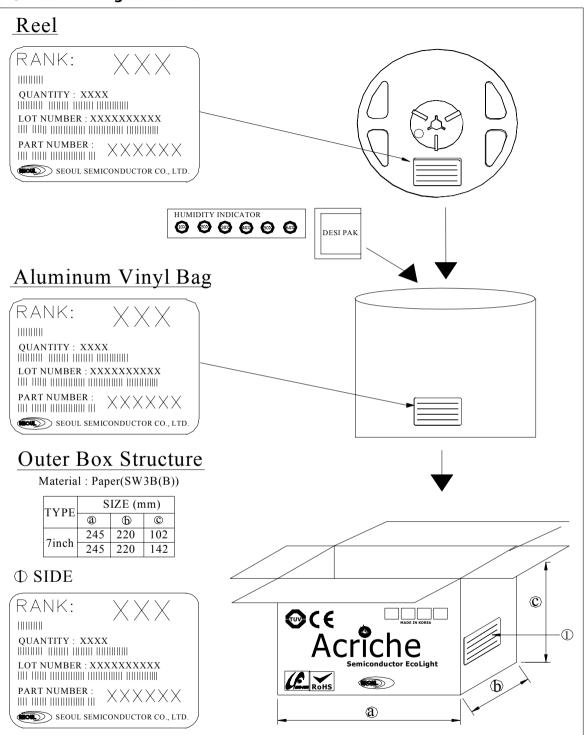
8. packing



- (1) Quantity : 2000pcs/Reel
- (2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be ± 0.2 mm
- (3) Adhesion Strength of Cover Tape : Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of 10° to the carrier tape
- (4) Package : P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package

• Reel Packing Structure

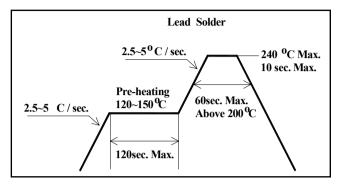




9. soldering

(1) Lead Solder

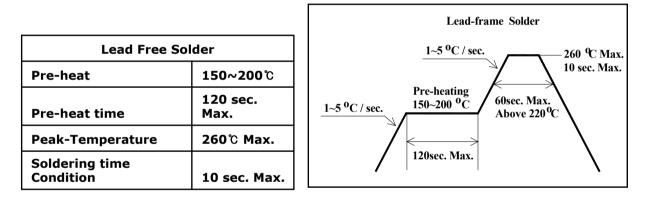
Lead Solder					
Pre-heat	120~150 ℃				
Pre-heat time	120 sec. Max.				
Peak-Temperature	240℃ Max.				
Soldering time Condition	10 sec. Max.				



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(2) Lead-Free Solder



(3) Hand Soldering conditions

Do not exceed 4 seconds at maximum 315°C under soldering iron.

(4) The encapsulated material of the LEDs is silicone.

Precautions should be taken to avoid the strong pressure on the encapsulated part.

So when using the chip mounter, the picking up nozzle that does not affect the silicone resign should be used.

Note : In case that the soldered products are reused in soldering process, we don't guarantee the products.

10. precaution for use

(1) Storage

In order to avoid the absorption of moisture, it is recommended to store in a dry box (or a desicator) with a desiccant. Otherwise, to store them in the following environment is recommended.

Temperature : 5°C ~30°C Humidity : maximum 70%RH

(2) Attention after open.

LED is correspond to SMD, when LED be soldered dip, interfacial separation may affect the light transmission efficiency, causing the light intensity to drop. Attention in followed; Keeping of a fraction

Temperature : $5 \sim 40^{\circ}$ C Humidity : less than 10%

(3) In the case of more than 1 week passed after opening or change color of indicator on desiccant, components shall be dried 10-12hr. at $60\pm5^{\circ}$ C.

(4) Any mechanical force or any excess vibration shall not be accepted to apply during cooling process to normal temperature after soldering.

(5) Quick cooling shall be avoided.

(6) Components shall not be mounted on warped direction of PCB.

(7) Anti radioactive ray design is not considered for the products.

(8) This device should not be used in any type of fluid such as water, oil, organic solvent etc. When washing is required, IPA should be used.

(9) When the LEDs are illuminating, operating current should be decided after considering the ambient maximum temperature.

(10) The LEDs must be soldered within seven days after opening the moisture-proof packing.

(11) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.

(12) The appearance and specifications of the product may be modified for improvement without notice.

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11. Handling of Silicone Resin LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



(2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.



(3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented.

This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.

(4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

(5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin. Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.



12. Reliability Test Item and Condition

Item	Reference	Test Condition	Duration / Cycle	Number of Damage
Thermal Shock	EIAJ ED- 4701	$T_a = -40^{\circ}$ C (30MIN) ~ 100°C (30MIN)	100 Cycle	0/22
Temperature Cycle	EIAJ ED- 4701	$T_a = -40^{\circ}$ C (30MIN) ~ 25°C (5MIN) ~ 100°C (30MIN) ~ 25°C (5MIN)	100 Cycle	0/22
High Temperature Storage	EIAJ ED- 4701	<i>T_a</i> =100°C	1000 Hours	0/22
High Temperature High Humidity Storage	EIAJ ED- 4701	<i>T_a</i> =85⁰C, RH=85%	1000 Hours	0/22
Low Temperature Storage	EIAJ ED- 4701	<i>T_a</i> =-40°C	1000 Hours	0/22
Operating Endurance Test	Internal Reference	<i>T_a</i> =25°C, <i>I_F</i> =20mA	1000 Hours	0/22
High Temperature High Humidity Life Test	Internal Reference	<i>T_a</i> =85ºC, RH=85%, <i>I_F</i> =15mA	300 Hours	0/22
High Temperature Life Test	Internal Reference	<i>T_a</i> =85°C, <i>I_F</i> =20mA	500 Hours	0/22
Low Temperature Life Test	Internal Reference	<i>T_a</i> =-40°C, <i>I_F</i> =20mA	1000 Hours	0/22
ESD(HBM)	MIL-STD- 883D	1KV at 1.5kΩ; 100pF	3 Time	0/22

Criteria for Judging the Damage

Itom	Symbol	Condition	Criteria for Judgement		
Item	Symbol	Condition	MIN	MAX	
Forward Voltage	V _F	<i>I_F</i> =20mA	-	$USL^{*1} \times 1.2$	
Reverse Current	I_R	$V_R = 5V$	-	$USL^{*1} \times 2.0$	
Luminous Intensity	I_V	<i>I_F</i> =20mA	$LSL^{*2} \times 0.5$	-	

Note : *1 USL : Upper Standard Level *2 LSL : Lower Standard Level